



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

August 11, 2026

IGI Report Number

Description

Shape and Cutting Style

Measurements

GRADING RESULTS

Carat Weight

Color Grade

Clarity Grade

ADDITIONAL GRADING INFORMATION

Polish

Symmetry

Fluorescence

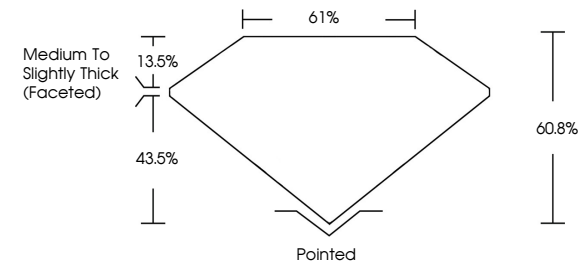
Inscription(s)

Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process. Type IIa

LG826655551

Report verification at igi.org

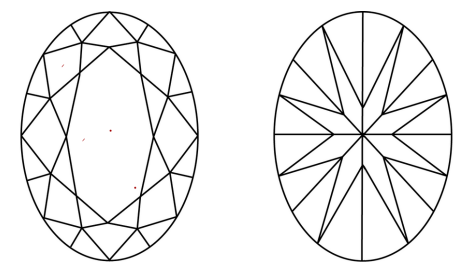
PROPORTIONS





Sample Image Used

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

FL IF VS¹⁻² VS¹⁻² SI¹⁻² I¹⁻³

Flawless Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included

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IGI Report No LG826655551

OVAL BRILLIANT

16.41 X 11.27 X 6.85 MM

8.09 CARATS

F

VVS 2

60.8%

61%

Medium to Slightly Thick (Faceted)

Pointed

EXCELLENT

EXCELLENT

NONE

IGI LG826655551

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